## Claims:

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◄. An integrated circuit comprising:

- 2 a wafer having circuitry disposed thereon;
- 3 \aplurality of conductors coupled to the wafer;
- 4 astructure that encapsulates and supports the wafer; and
- 5 magnetic material disposed to alter an inductance associated with at least one
- 6 of the plurality of conductors.
- 1 2. The integrated circuit of claim 1, wherein the magnetic material is at least
- 2 partially disposed within the structure.
- 1 3. The integrated circuit of claim 1, wherein the magnetic material is substantially
- 2 homogeneously disposed throughout the structure.
- I 4. The integrated circuit of claim wherein at least a portion of the magnetic
- 2 material is disposed external to the structure.
- 1 5. The integrated circuit of claim 1, wherein the magnetic material comprises a
- 2 ferromagnetic material.
- 1 6. The integrated circuit of claim 1, wherein the magnetic material comprises a
- 2 ferrite material.

- The integrated circuit of claim 1, further comprising at least one choke structure formed of the magnetic material, wherein each chock structure associates with at least one respective conductor of the plurality of conductors.
- The integrated circuit of claim 1, wherein the magnetic material forms a plurality of choke structures each of the choke structures being associated with at least one respective conductor of the plurality of conductors
- The integrated circuit of claim 7, wherein the structure comprises a dielectric material encapsulating at least a portion of the choke structures.
- 1 10. The integrated circuit of claim 7, wherein at least some of the choke structures 2 are disposed external to the structure.

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